



AND127CR

GaAlAs Red Light Emission T-1 Package (3 mm)

Features

- Peak wavelength ($\lambda p = 660 \text{ nm}$) high bright emission
- All plastic mold type, clear lens
- Low drive current: 10-20 mA recommended
- Excellent On-Off contrast ratio
- Fast response time, capable of pulse operation

Maximum Ratings $(T_a = 25^{\circ}C)$

Characteristics	Symbol	Rating	Unit
Forward Current	I _F	40	mA
Reverse Voltage	V _R	4	V
Power Dissipation	P _D	110	mW
Operating Temperature Range	T _{Opr}	-40 to 85	°C
Storage Temperature Range	T _{Stg}	-40 to 100	°C

Electro-Optical Characteristics (T_a = 25°C)

Characteristics	Symbol	Test Condition	Minimum	Typical	Maximum	Unit
Forward Voltage	V _F	I _F = 20 mA	_	2.1	2.4	V
Reverse Current	I _R	V _R = 4 V	_	-	100	μΑ
Luminous Intensity	I _V	I _F = 20 mA	400	630	-	mcd
Peak Emission Wavelength	l _P	I _F = 20 mA	_	660	_	nm
Spectral Line Half Width	Δλ	I _F = 20 mA	_	20	=	nm
Dominant Wavelength	λd	I _F = 20 mA	_	640	-	nm
Full Viewing Angle	θ	I _V = 1/2 Peak	_	30	_	degree

Precaution

Please be careful of the following:

- Soldering temperature: 260°C max Soldering time: 5 sec. max
 - Soldering portion of lead: up to 1.6 mm from the body of the device
- 2. The lead can be formed up to 5 mm from the body of the device without forming stress. Soldering should be performed after the lead forming.



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